

HLW8012 Datasheet

REV 1.3

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CATALOG

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History Revision Record

| Date | Revision Record | Version |
|------------|--|---------|
| 2013-1-2 | Initial Version | REV 1.0 |
| 2014-6-20 | Change Company Address | REV 1.1 |
| 2014-8-01 | Change Pin Nam: VIN To V1N, VIP To V1P | REV 1.2 |
| 2015-11-11 | Change Digital Characteristic: DCLK To MCLK | REV 1.3 |
| | Add description of current channel and voltage channel: $\boldsymbol{V}_{\text{peak}}$ | |



1 Function Description

HLW8012 is single phase multifunction metering chip. The high frequency pulse CF is provided for the energy measurement and the high frequency CF1 for indicating the effective value of the current or the effective value of the voltage. The chip uses SOP8 package.

1.1 Main Features

- High frequency pulse CF, indicating active power, meet the accuracy of 50/60Hz IEC 687/1036
 standards, in the range of 1000:1 to reach 0.2% accuracy.
- High frequency pulse CF1 can be configured to output current or voltage RMS, in the range of 500:1 to reach of 0.5% accuracy.
- Built-in power supply monitoring circuit, when the power supply voltage is low to 4V, the chip will be reset.
- Built-in 2.43V voltage reference source; 5V power supply, operating current is less than 3mA.
- Application areas: The occasion of measuring the voltage, current and power, such as single-phase multi-function meter, smart socket, digital meter, smart street lamps, small appliances, etc.

1.2 Structure Description

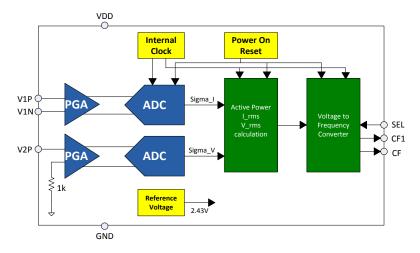


Figure 1 Function block diagram



1.3 PIN CONFIGURATION

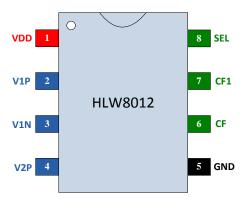


Figure 2 Pin Configuration

Table 1: PIN FUNCTION DESCRIPTIONS

| Pin No. | Pin Name | Input/Output | Description |
|---------|----------|--------------|--|
| 1 | VDD | Power Supply | Power Supply |
| 2, 3 | V1P, V1N | Input | Analog Inputs for Channel 1(Current Channel) with maximum differential signal level of ±43.75mV(V _{peak}). |
| 4 | V2P | Input | Analog Input for Channel 2(Voltage Channel) with maximum single signal level of ±700mV(V _{peak}). |
| 5 | GND | Ground | Ground |
| 6 | CF | Output | Output active high frequency pulse, duty cycle 50% |
| 7, | CF1 | Output | SEL=0, Output current effective, duty cycle 50%; SEL=1, Output voltage RMS, duty cycle 50%; |
| 8 | SEL | Input | Configure RMS output type, with drop resistor |



2 Feature Description

2.1 Recommended Operating Conditions

| Parameter | Symbol | Min | Туре | Max | Unit |
|-----------------------------|----------------|-----|------|-----|------|
| Positive Power Supply | VDD | 4.5 | 5.0 | 5.5 | V |
| Operation Temperature Range | T _A | -40 | - | +85 | °C |

2.2 Analog Characteristic

 $VDD = 5 V \pm 10\%$; GND = 0 V

| | Parameter | Symbol | Min | Туре | Max | Unit |
|--|-----------------------|-------------------------|-----|------|-----|-------|
| ACCURACY | | | | | | |
| Active Power | Full Gain Range | P _{Active} | _ | ±0.2 | _ | % |
| | Input Range 0.1%~100% | r Active | | ±0.2 | _ | 70 |
| Current RMS | Full Gain Range | I _{RMS} | _ | ±0.5 | _ | % |
| | Input Range 0.2%~100% | IRMS | | 10.5 | _ | /0 |
| Voltage RMS | Full Gain Range | V_{RMS} | | ±0.5 | | % |
| | Input Range 0.2%~100% | V _{RMS} | - | ±0.5 | - | /0 |
| Analog Input | (All Channel) | | | | | |
| Common-mode Range | | | -1 | - | 1 | V |
| Crosstalk in voltage channel | | | | -100 | _ | dB |
| When full range in current channel(50, 60Hz) | | | | -100 | _ | ив |
| Input Capacitar | Input Capacitance | | - | 6.4 | - | pF |
| Input Impedan | ce | | | | | |
| | Current Channel | EII | | 500 | - | kΩ |
| | Voltage Channel | | | 6 | | ΜΩ |
| Input-Referred | Noise | | | | | |
| | Current Channel | Nı | - | - | 2 | μVrms |
| | Voltage Channel | | - | - | 20 | μVrms |
| Power Supply | | | | | | |
| Supply Current | IA+ID | | | 3 | - | mA |
| Power Consum | ption (VDD = 5 V) | PC | - | 15 | | mW |



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| Low Threshold of Power-Down Voltage | PMLO | - | 4 | - | V |
|--------------------------------------|------|---|-----|---|---|
| High Threshold of Power-Down Voltage | PMHI | - | 4.3 | - | ٧ |

2.3 Built-In Reference

| Parameter | Symbol | Min | Туре | Max | Unit |
|-------------------------|--------------------|------|-------|-------|-------|
| Reference Voltage | VREF | +2.3 | +2.43 | +2.55 | V |
| Temperature Coefficient | TC _{VREF} | - | 25 | - | ppm/℃ |

2.4 Digital Characteristic

VDD = 5 V, GND = 0 V

| Param | eter | Symbol | Min | Туре | Max | Unit |
|--------------------------|----------------|------------------|----------|--------|------|------|
| BUILT-IN CLOCK | | | | | | |
| Frequency | | MCLK | 3.04 | 3.579 | 4.12 | MHz |
| Duty Cycle | | | 30 | 50 | 70 | % |
| FILTER | | | | | | |
| Sampling Rate (DCLK= | MCLK/4) | | - | MCLK/4 | - | Hz |
| Digital Filter Output Ra | OWR | - | MCLK/128 | - | Hz | |
| High-Pass Filter Bandwi | dth (-3dB) | | - | 0.543 | - | Hz |
| INPUT | | | | | | |
| Input High Voltage | (VDD=5V) | V _{IH} | 0.8VDD | - | - | V |
| Input Low Voltage | (VDD=5V) | V _{IL} | - | - | 0.8 | V |
| Input Leakage | | I _{in} | - | ±10 | - | μΑ |
| OUTPUT | | | | | | |
| Output High Voltage | (lout = +5 mA) | V _{OH} | VDD-0.5 | - | - | V |
| Output Low Voltage | (Iout=-5 mA) | V _{OL} | - | - | 0.5 | V |
| Capacitance Of Digital (| Output Pin | C _{OUT} | - | 5 | - | pF |

2.5 Switching Characteristic

Pin SEL is digital input port, the duty cycle of CF and CF1 pluses are 50%.



2.6 ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Min | Туре | Max | Unit |
|-----------------------------|-------------------|------|------|---------|------|
| Digital Supply | VDD | -0.3 | - | +6.0 | V |
| Analog Supply | VDD | -0.3 | - | +6.0 | V |
| VDD to GND | | -0.3 | - | +6.0 | V |
| V1P, V1N, V2P to GND | | -2 | | +2 | V |
| Analog Input Voltage | V _{INA} | -0.3 | - | VDD+0.3 | V |
| Digital Input Voltage | V _{IND} | -0.3 | - | VDD+0.3 | V |
| Digital Output Voltage | V _{OUTD} | -0.3 | - | VDD+0.3 | V |
| Operating Temperature Range | T _A | -40 | - | 85 | °C |
| Storage Temperature Range | T _{stg} | -65 | - | 150 | °C |



3 Application

3.1 HLW8012 Typical application

As shown in Figure 3, the power supply the HLW8012 should be in parallel with two small capacitors to filter out the noise from the grid. The signal of current channel is provided by the current diverter. The signal of voltage channel is provided by the resistor network. CF, CF1, SEL connect to the input port of the MCU. MCU measure the pulse periods of CF and CF1, then calculate the active power, current RMS and voltage RMS.

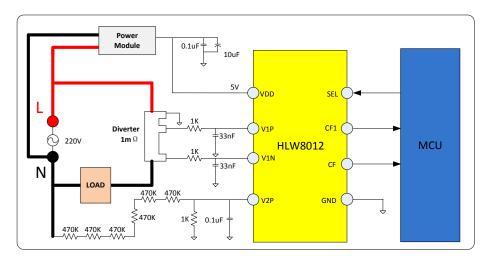


Figure 3 Typical application

3.2 Frequency of CF、CF1

The internal DSP of HLW8012 Integrates the PGA. After frequency conversion, the output frequency of active power, current RMS and voltage RMS can be calculated by the following formula:

(1) Active Power:
$$F_{CF} = \frac{V1 \times V2 \times 48}{V_{REF}^2} \times \frac{f_{osc}}{128}$$

(2) Current RMS:
$$F_{CFI} = \frac{V1 \times 24}{V_{REF}} \times \frac{f_{osc}}{512}$$

(3) Voltage RMS:
$$F_{CFU} = \frac{V2 \times 2}{V_{REF}} \times \frac{f_{osc}}{512}$$

V1: Voltage of the current channel

V2: Voltage of the voltage channel

 f_{osc} : Frequency of built-in oscillator is 3.579MHz



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 V_{REF} : Voltage of the built-in reference is 2.43V

3.3 Threshold and Creeping Prevention

HLW8012 uses the anti-creep new algorithm, as long as the input signal is greater than the noise, the module to normal measurement.

3.4 Built-In Oscillator

The frequency of the built-in oscillator is 3.579MHz, the power supply rejection ratio is less than <0.01/V.

3.5 Built-In Reference

HLW8012 Integrated high precision band-gap reference source, the voltage of the reference is 2.43V.



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4 HLW8012 Package

HLW8012 uses SOP8 package, the information is shown in Figure 4:

| Size Label | Min (mm) | Max (mm) | Size Label | Min (mm) | Max (mm) |
|---------------------|-------------|---|--------------------------------------|--------------|------------|
| A | 4.95 | 5.15 | C3 | 0.05 | 0.20 |
| A1 | 0.37 | 0.47 | C4 | | TYP |
| A2 | 1.27 | TYP | D | 1.05 | iTYP |
| A3 | 0.41 | TYP | D1 | 0.40 | 0.60 |
| В | 5.80 | 6.20 | R1 | 0.07 | TYP |
| B1 | 3.80 | 4.00 | R2 | 0.07 | 'TYP |
| B2 | 5.0 | | 81 | 17° | TYP |
| С | 1.30 | 1.50 | 02 | 13° | TYP |
| C1 | 0.55 | 0.65 | 83 | 4° | ТҮР |
| C2 | 0.55 | 0.65 | 84 | 12 | ТҮР |
| фФ | 1.5*0.05 A1 | D D D D D D D D D D D D D D D D D D D | ±0.05 0.2±0.05 5 €4 | | "X" |
| υ <u>τ</u> <u>ε</u> | | <u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u> </u> <u> </u> | <u>8</u> <u>3</u> ∠ _{R1} | B2 DELTA "X" |)84 B1 |

Figure 4 Package

